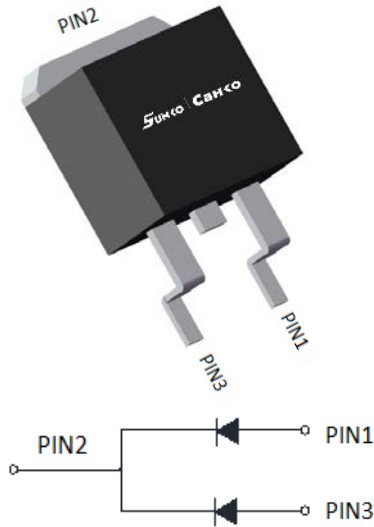


## Schottky Diodes



### Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-263  
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRB1045CTS
Device marking code			MBRB1045CTS
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, Tc (FIG.1)	IO	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	IFSM	A	100
Current Squared Time @1ms≤t≤8.3ms Tj=25°C,	I²t	A²s	41
Storage Temperature	Tstg	°C	-55 ~ +150
Junction Temperature	Tj	°C	-55 ~ +150

### ■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRB1045CTS
Maximum instantaneous forward voltage drop per diode	V <sub>FM</sub>	V	I <sub>FM</sub> =5.0A	0.65
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>R1</sub>	mA	V <sub>RM</sub> =V <sub>R1</sub> Ta=25°C	0.2
	I <sub>R2</sub>		V <sub>RM</sub> =V <sub>R2</sub> Ta=100°C	20

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS

# MBRB1045CTS

## ■ Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBRB1045CTS
Thermal Resistance	Between junction and case	RθJ-C	°C/W	2.0

## ■ Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRB1045CTS	Approximate 1.43	50	2000	8000	Tube
MBRB1045CTS	Approximate 1.43	1000	2000	10000	Reel

## ■ Characteristics (Typical)

FIG1:Io -Tc Curve

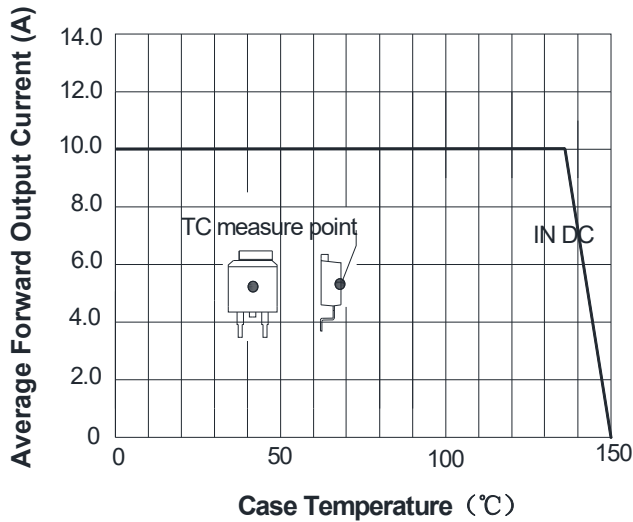


FIG2: Surge Forward Current Capability

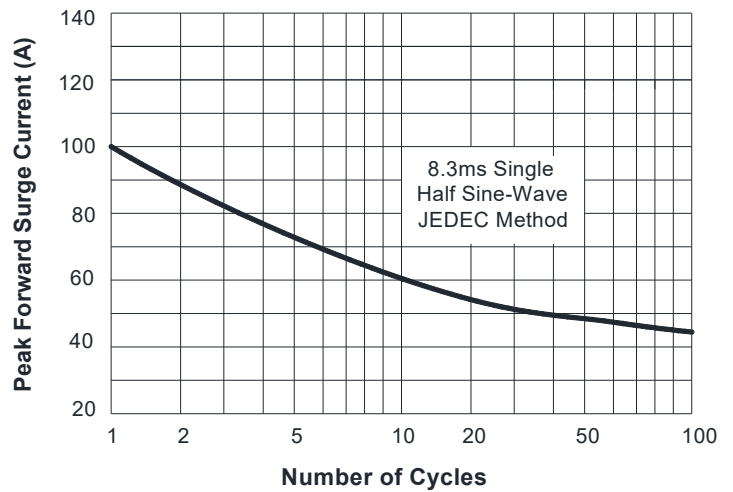


FIG3: Forward Voltage

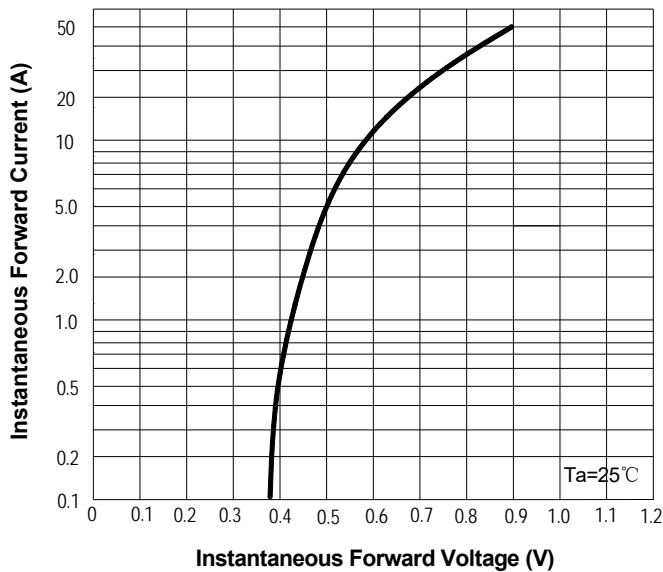
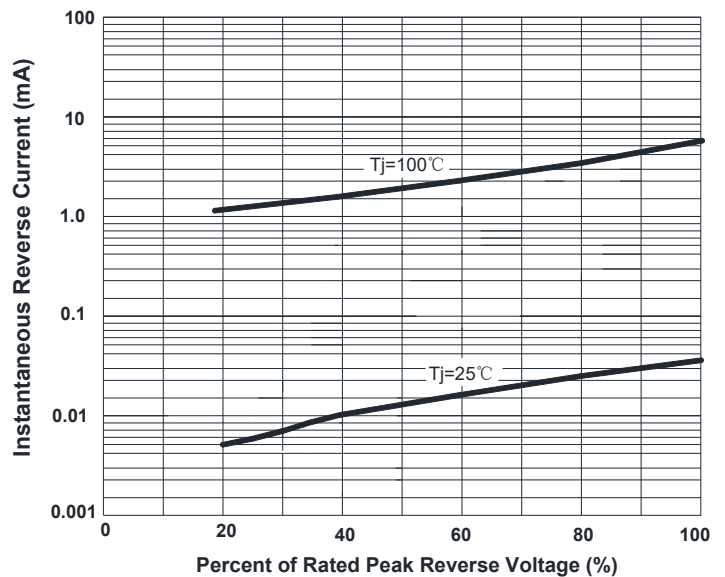
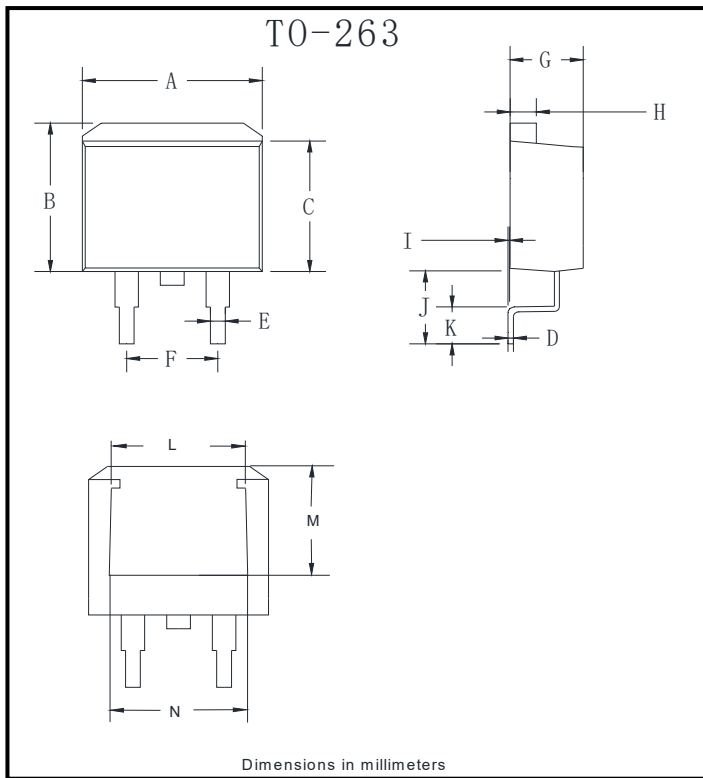


FIG4: Typical Reverse Characteristics

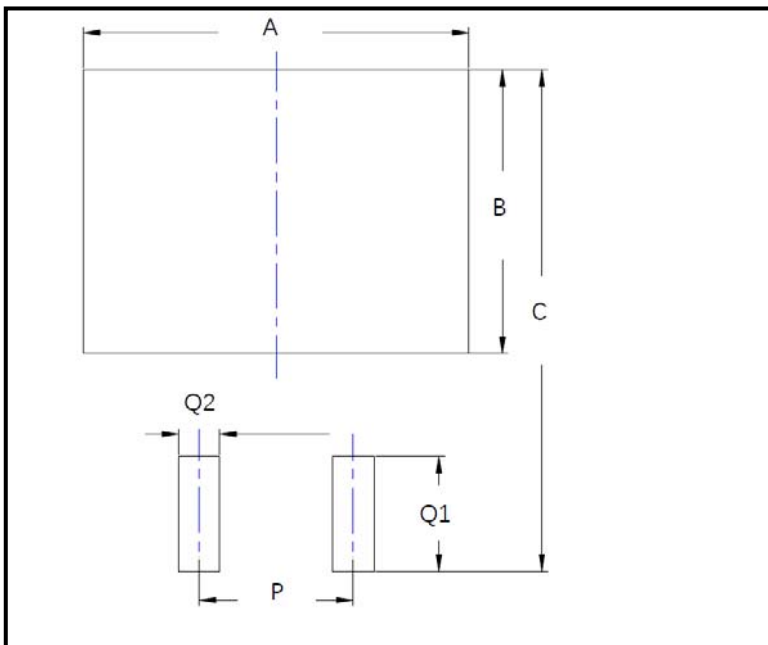


■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05
K	1.79	2.79
L	7.3	7.9
M	6.2	6.8
N	7.6	8.2

■ Suggested Pad Layout



Dim	Millimeters
A	12.7
B	9.4
C	16.6
P	5.08
Q1	3.8
Q2	1.35

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